## TOSHIBA

TOSHIBA Bi-CMOS Integrated Circuit Silicon Monolithic

# TB9067FNG

## Automotive 3-Phase Brushless Motor Pre-Driver

The TB9067FNG is an automotive three-phase brushless DC motor pre-driver incorporating a 120-degree commutation decoding logic.

## Features

- 3-phase 120-degree rectangular commutation control
- PWM chopper control
- External P-channel/N-channel MOS drive output (3 phases with 6 outputs)
- Internal PWM drive/external direct drive (selectable)
- PWM pulse input control/DC level input control (selectable)
- Forward/Reverse switch capability
- Low-side driver output PWM control
- Overcurrent protection: double detection (current limiter/overcurrent detection)
- 5.12-MHz oscillator
- 5-V regulated voltage
- Operating temperature range: -40 to 125°C
- Compact flat package: 24-pin SSOP (0.65-mm pitch)
- The product(s) is/are compatible with RoHS regulations (EU directive 2011 / 65 / EU) as indicated, if any, on the packaging label ("[[G]]/RoHS COMPATIBLE", "[[G]]/RoHS [[Chemical symbol(s) of controlled substance(s)]]", "RoHS COMPATIBLE" or "RoHS COMPATIBLE, [[Chemical symbol(s) of controlled substance(s)]]>MCV").





## **TOSHIBA**

## **Block Diagram**



Note: In the block diagram, part of the functional blocks or constants may be omitted or simplified for explanatory purposes.

## Application Circuit Example (Operating Mode 1)



- Note: In the application circuit example, part of the functional blocks or constants may be omitted or simplified for explanatory purposes.
- Note: Ensure that the IC is mounted correctly as specified. Failing to observe the correct mounting procedure or requirements may damage the IC or target equipment.
- Note: The capacitor connected to the Source pin of the Pch FET is for absorbing disturbance noise, voltage fluctuation by load change, etc. Connect it as close to the Source pin of the Pch FET as possible.
- Note: The application circuit shown above is not intended to guarantee mass production. A thorough evaluation is required when designing an application circuit for mass production. Toshiba does not grant any license to any industrial property rights by providing these examples of application circuits.
- Note: Utmost care is necessary in the design of the output OUTXX, VB ,VDD and GND lines since the IC may be destroyed in case of a short-circuit across outputs, a short-circuit to power supply, or a short-circuit to ground.

Note: Please use to make a short both VREG and VDD always. Possibly make a malfunction to potential difference occurs between VREG and VDD.

## TOSHIBA

## **Pin Assignment**



## **Pin Description**

Pin No.	Symbol	Pin Description
1	SEL1	Operating mode setting input Low: Mode 1 Middle: Mode 2 (including the open state of the pin) High: Mode 3
2	TEST	Test mode select input (must be shorted to GND in normal operation) Low: User mode High: Test mode
3	NDG	Error monitor output/forced off input [Output] Low: Error detected High: Normal state [Input] Low: Pre-driver is forcibly turned off (fixed to High/Low) High: Don't care
4	SU	U-phase sensor signal input
5	SV	V-phase sensor signal input
6	SW	W-phase sensor signal input
7	SEL2	Start mode setting input (for the operating mode 1 or 3) Low: Rapid start High: Slow start (normal speed) Motor rotation direction setting input (for the operating mode 2) Low: Two-wire control mode High: Single-wire control mode
8	cw/ccw	Rotation direction control *For additional information, see Chapter 2. Pre-Driver Output Waveforms Low: Reverse High: Forward
9	PGND	Pre-driver power ground (must be shorted to the GND pin externally)
10	OUL	U-phase output pin of the low-side pre-driver
11	OVL	V-phase output pin of the low-side pre-driver
12	OWL	W-phase output pin of the low-side pre-driver
13	OUH	U-phase output pin of the high-side pre-driver
14	OVH	V-phase output pin of the high-side pre-driver
15	OWH	W-phase output pin of the high-side pre-driver
16	BIAS	Bias voltage
17	PWMIN	PWM signal input
18	GND	IC ground (except for the pre-drivers)
19	PWMOUT	PWM signal output/DC data input
20	SEL0	Full drive enable/disable where PWMIN = Low Low: Enable High: Disable
21	VREG	5-V regulated voltage
22	TVIN	Input signal for monitoring the external analog voltage (high input voltage causes an error detection to be occurred)
23	VDD	Power supply for the internal logic IC (must be shorted to VREG externally)
24	COMPP	Input signal for monitoring the external motor driver current (any error is detected if the input marks high voltage)

#### 1. Basic Operation

The PWM signal is applied to the TB9067FNG as a command signal. The output PWM signal duty cycle generated from the said input PWM activates the three-phase motor driver.

According to the output PWM types, the TB9067FNG has the two drive modes: the internal PWM drive mode and the external direct drive mode. The input PWM signal has the following characteristics ranges:

- Frequency: Up to 4 kHz (for internal PWM drive) Up to 23 kHz (for external direct drive)
- PWM duty: 0 to 100%
- Voltage amplitude: 0 V to bias voltage

The output PWM signal generated from the input PWM signal is sent out from the pre-drivers according to the sensor signal from the motor. This runs the three-phase brushless motor.

TOSHIBA

## Functional Description

#### 2. Pre-Driver Output Waveforms

(1) Forward rotation mode (CW/CCW input = High)



Note: If a combination of the sensor inputs is other than the combination shown above (i.e. all Low or all High), the motor driver is turned off (with the high-side pre-driver output = all High, low-side pre-driver output = all Low).



(2) Reverse rotation mode (CW/CCW input = Low)







(3) Rotation direction switchover (CW/CCW input = High to Low)



(4) Rotation direction switchover (detailed timing chart)



#### 3. Operating Modes

The SEL1 pin and SEL2 pin serve to control the TB9067FNG operating mode setting.

The operating mode is classified into two drive modes as shown below. Each of these two modes is further classified into the two operating modes with the different types of control.

#### 3.1 Internal PWM Drive Mode

According to the input PWM duty applied through the PWMIN pin, a PWM waveform is internally generated and sent out from the pre-drivers. The generated PWM waveform has a carrier frequency of 20 kHz typical.

The internal PWM drive mode has the two types of operating mode determined by the active level of the PWMIN input.

1) Operating mode 1 (active-Low)

The input voltages lower than the PWMIN input threshold (2/5 VREG typ.) are the active level in this mode. In operating mode 1, the PWMIN pin will provide a built-in pull-up resistor of 100 k $\Omega$  typical.

2) Operating mode 3 (active-High)

The input voltages higher than the PWMIN input threshold (2/3 BIAS typ.) are the active level in this mode. In operating mode 3, the PWMIN pin will provide a built-in pull-down resistor of 100 k $\Omega$  typical.

#### 3.2 External Direct Drive Mode

The input PWM waveform applied through the PWMIN pin is directly sent out from the pre-drivers. (This operating mode is hereinafter referred to as the Operating Mode 2.)

The operating mode 2 provides the two different ways of controlling the pre-driver ON duty and the rotation direction, according to the input modes.

1) Single-wire control

A PWM duty configuration signal superimposed with motor rotation direction information is applied on the PWMIN pin. The pre-driver ON duty and the rotation direction are thereby determined through a single input. (In this mode, the CW/CCW pin configuration is disabled.)

The PWMIN pin in single-wire control mode will provide both a built-in pull-up resistor of 100 k $\Omega$  typical and a built-in pull-down resistor of 100 k $\Omega$  typical.

2) Two-wire control

A PWM duty configuration signal is applied to the PWMIN pin while the motor direction control signal is applied to the CW/CCW pin. The pre-driver ON duty and the rotation direction are thereby controlled separately.

The PWMIN pin in this mode provides a built-in pull-up resistor of 100 k $\Omega$  typical.

Pin Conf SEL1	iguration SEL2	Operating Mode		Output Frequency of Motor Rotation the Pre-Driver Direction Control		Active Level of the PWMIN Pin	PWMIN Built-In Resistor
Low	_	Mode 1		Internally generated 20 kHz	Controlled by the CW/CCW input	2/5 VREG or lower	Pull-up
Middle	High Middle		Single-wire control	PWMIN pin Direct	Internally generated from the PWMIN input	2/5 VREG or lower and 2/3 BIAS or higher	Pull-up and pull-down
(Open)	Low	MODe 2	Two-wire control	PWMIN pin Direct	Controlled by the CW/CCW input	2/5 VREG or lower	Pull-up
High	_	Mode 3		Internally generated 20 kHz	Controlled by the CW/CCW input	2/3 BIAS or higher	Pull-down

#### [Operating Modes]

Note: A hyphen ( — ) indicates Don't care (start mode select function)



#### 3.3 Details of Operating Modes

(1) Operating mode 1

From the Low level input duty of the PWM signal sent on the PWMIN pin, the TB9067FNG internally generates a carrier frequency of 20 kHz typical to run the pre-drivers (active-Low).

The PWM input signal sent on the PWMIN pin is inverted and sent out from the PWMOUT pin. The inverted data is smoothed by the built-in output resistor of 200 k $\Omega$  (typ.) at the PWMOUT pin and the external capacitor. The smoothed voltage is then taken into the AD converter and processed through the digital filter to determine the pre-driver ON duty (except for the rapid start mode).

Applying the DC voltage directly to the PWMOUT pin, too, allows the pre-driver ON duty control.



Note: Timing charts may be simplified to clarify the descriptions of features and operations.

(2) Operating mode 3

From the Low level input duty of the PWM signal sent on the PWMIN pin, the TB9067FNG internally generates a carrier frequency of 20 kHz typical to run the pre-drivers (active-High).

The PWM signal sent on the PWMIN pin is sent out on the PWMOUT pin in phase. The said signal is smoothed by the built-in output resistor of 200 k $\Omega$  (typ.) at the PWMOUT pin and the external capacitor. The smoothed voltage is then taken into the AD converter and processed through the digital filter to determine the pre-driver ON duty (except for the rapid start mode).

Applying the DC voltage directly to the PWMOUT pin, too, allows the pre-driver ON duty control.

PWMIN pin	BIAS
PWMOUT signal (IC internal signal)	VDD 0V
PWMOUT pin output waveform (CR smoothing waveform)	VDD 0V
Low-side pre-driver High output duty	100% 0%
Low-side pre-driver output waveform	BIAS 0V

## TOSHIBA

## **Functional Description**

(3) Operating mode 2

The PWM input sent on the PWMIN pin directly runs the pre-drivers in this mode. The pre-driver ON duty and output frequency depend on the said PWM input.

Besides, the TB9067FNG provides the two types of input mode (single- and two-wire controls), depending on how to control the motor rotation direction.

1) Single-wire control

The PWM waveform superimposed with two pieces of information; the pre-driver ON duty and the motor rotation direction, is sent on the PWMIN pin. The TB9067FNG runs the pre-drivers in accordance with each pulse of the High level input (more than 2/3 BIAS typ.) and Low level input (less than 2/5 VREG typ.) of the PWM wave.

The motor rotates forward when the High level input of the PWM wave is detected (like in the case that CW/CCW input = High) while it rotates in reverse direction when a Low level input of the PWM wave is detected (like in the case that CW/CCW input = Low). The CW/CCW pin input should be disabled. Every time the motor rotation direction is changed, a dead time (50  $\mu$ s typ.) is automatically inserted.





2) Two-wire control

The pre-driver ON duty information and motor rotation direction information are separately sent in. The pre-driver ON duty is sent in as a PWM signal on the PWMIN pin. The PWM signal Low-level input (less than 2/5 VREG typ.) activates the pre-drivers (active-Low).

On the other hand, the motor rotation direction is configured using the CW/CCW pin.

Every time the motor rotation direction is changed, a dead time (50  $\mu$ s typ.) is automatically inserted.

		1		Ī		Ī		1				1		1			BIAS
PWMIN pin					 	 					+				 	2/5×VREG	
	 		<b>.</b>				L		L		<b>.</b>		J				0V
PWM signal (IC internal signal)				ļ													0V
CW/CCW signal					 			-							 		- VDD
(IC internal signal)	 				 	 											0V
High-side pre-driver (e.g. OLIH)															 		- BIAS
(e.g. 0011)	 				 	 								-	 		0V
High-side pre-driver (e.g. OVH)	 				 	 		Ē									BIAS
(0.g. 0111)															 		0V
Low-side pre-driver	 	Γ						Π							 		- BIAS
(0.g. 00L)		<b>_</b>		<b>.</b>		<b>.</b>				+							0V
Low-side pre-driver (e.g. OVL)	 				 	 				Ī				<u> </u>			BIAS
								-			<b>I</b>	<b></b> ]	L	<b></b>	LL		0V
								D	ead Tim	ne -							

#### 4. Function Configuration

The SEL0 and SEL2 pins serve to configure the following functions:

- Disabling the full drive (SEL0)
- Motor start mode setting (SEL2)

#### 4.1 Disabling the Full Drive (SEL0)

Driving the SEL0 pin High allows disabling the full drive of the motor driver.

In order to protect the motor driver from the excessive PWM duty configuration due to the PWMIN pin destruction (like a grounding fault), the motor driver output gets forced off (with the high-side pre-driver output High, low-side pre-driver output Low) if more than 95% PWM duty (typ.) is applied to the PWMOUT pin.

The motor driver resumes the output when the PWM duty cycle drops under 90%. (For details, refer to 5-7. Full Drive Detection)

#### [Full Drive Disable Configuration]

Pin Configuration	100% Drive	Demarka
SEL0	100% Drive	Remaiks
Low	Enable	
High	Disable	

SEL0 = Low

SEL0 = High



#### 4.2 Motor Start Mode Setting (SEL2)

Pulling the SEL2 pin Low allows the motor to start up in a precipitous curve (Rapid start). If the SEL2 pin is driven Low upon power-on, a digital filter processing is eliminated for 0.3 sec (typ.) from a release of a detection of the low VREG voltage, and the data converted by the AD converter is thereby used as a PWM duty without being changed.

The combination of this capability and the external capacitor at the PWMOUT pin allows the start mode to be selected as shown in the figure below. Provided, however, that this function is available only in operating mode 1 and operating mode 3.

Pin Con	figuration	Operating Meda	Stort Mada	Bomarka				
SEL1	SEL2	Operating Mode	Start Mode	rendiks				
Low	Low	Mode 1	Rapid start					
LOW	High	Mode I	Normal start					
Middle	Low	Modo 2		Two-wire control where SEL2 = Low				
(Open)	High	Mode 2	(PWMIN Direct)	Single-wire control where SEL2 = High				
High	Low	Modo 3	Rapid start					
підп	High	wode 5	Normal start					

Note: A hyphen ( --- ) indicates" Don't care"

#### SEL2 = High, Capacitance = 1 $\mu$ F

#### SEL2 = Low, Capacitance = 1 $\mu$ F









Note: The charts shown above present the theoretical figures for the PWMIN pin characteristics when the pin is fixed to High or Low (100% duty cycle). If the pulse input is used, the figures will change. If pulses are applied to the PWMIN pin, smoothing by the external capacitor at the PWMOUT pin is required.



#### 5. Error Detection Capability

The TB9067FNG provides the following eight error detection functions:

- External overcurrent detection for the motor driver
- External thermal detection for the motor driver
- IC thermal detection
- BIAS overvoltage detection
- BIAS undervoltage detection
- VREG undervoltage detection (5-V output)
- Full drive detection
- External forced off input

#### 5.1 External Overcurrent Detection for the Motor Driver

The external shunt resistor on the motor driver is monitored at its both ends by the COMPP pin to detect the overcurrent state of the motor driver.

The overcurrent detector has two levels of threshold. Their characteristics are as follows:

1) Overcurrent detection 1 (motor lock detection)

If once an overcurrent state (more than 100 mV typ.) is detected, the low-side driver gets forced off (the high-side pre-driver maintains its output state while the low-side pre-driver output is changed to Low). After the off state of 50  $\mu$ s (typ.), the low-side driver resumes the output.

The noise filter mounted on the COMPP pin will be configured with 3  $\mu$ s (typ.) for this function.



Note: Timing charts may be simplified to clarify the descriptions of features and operations

2) Overcurrent detection 2 (load short-circuit failure detection)

If once an overcurrent state (more than 200 mV typ.) is detected, both the high-side and low-side drivers get forced off (the high-side pre-driver output is changed to High while the low-side pre-driver output is changed to Low). After the off state of 200  $\mu$ s (typ.), the drivers resume the outputs. During the overcurrent detection 2, the PWMOUT pin is forcibly fixed to Low, and the NDG pin output is pulled Low.

If the overcurrent is repeatedly detected at intervals of within 50 ms (typ.), the state is recognized as one continuous overcurrent; and if this state continues for 0.6 sec (typ.), the motor driver output is fixed to off.

If the power voltage is turned off (upon undervoltage detection for VREG), the fixed off of the motor driver is released.

The noise filter mounted on the COMPP pin will be configured with 1  $\mu$ s (typ.) for this function.





#### 5.2 External Thermal Detection for the Motor Driver

The external thermistor on the motor driver is monitored by the TVIN pin to detect the overtemperature state of the motor driver.

Once the overtemperature (more than 0.44 VREG typ.) is detected, both the high-side and low-side drivers are turned off (the high-side pre-driver output is changed to High while the low-side pre-driver output is changed to Low). The drivers resume the outputs if the thermal detection is released due to the lowered temperature.

While the external thermal detection is running, the PWMOUT pin is fixed to Low, and the NDG pin output is pulled Low.



The TVIN pin has a noise filter of 10  $\mu$ s (typ.).

Note: Timing charts may be simplified to clarify the descriptions of features and operations

#### 5.3 IC Thermal Detection

Once the overtemperature state (more than 165°C typ.) of the IC is detected, the drivers get turned off (the high- and low-side pre-drivers with Hi-z outputs). The drivers resume the outputs when the thermal detection is released due to the lowered temperature.

During the IC thermal detection, the PWMOUT pin is forcibly fixed to Low, and the NDG pin output is pulled Low.



Note: Timing charts may be simplified to clarify the descriptions of features and operations

#### 5.4 BIAS Overvoltage Detection

If once the BIAS overvoltage (more than 27 V typ.) is detected, the drivers are turned off (the high-side pre-driver output is changed to High while the low-side pre-driver output is changed to Low). The drivers resume the outputs when the overvoltage detection is released.

During the BIAS overvoltage detection, the PWMOUT pin is forcibly fixed to Low, and the NDG pin output is pulled Low.



Note: Timing charts may be simplified to clarify the descriptions of features and operations

#### 5.5 BIAS Undervoltage Detection

If once the BIAS undervoltage (less than 5.5 V typ.) is detected, the drivers are turned off (the high-side pre-driver output is changed to High while the low-side pre-driver output is changed to Low). The drivers resume the outputs when the undervoltage detection is released.

During the BIAS undervoltage detection, the PWMOUT pin is forcibly fixed to Low, and the NDG pin output is pulled Low.



Note: Timing charts may be simplified to clarify the descriptions of features and operations

OSHIRA

#### 5.6 VREG Undervoltage Detection (5-V output)

If once the VREG undervoltage (less than 4.5 V typ.) is detected, the control logic is initialized, and the drivers are turned off (the high-side pre-driver output is changed to High while the low-side pre-driver output is changed to Low). The drivers resume the outputs when the VREG undervoltage detection is released.

During the VREG undervoltage detection, the PWMOUT pin is forcibly fixed to Low, and the NDG pin output is pulled Low.



Note: Timing charts may be simplified to clarify the descriptions of features and operations

#### 5.7 Full Drive Detection

If the PWMOUT pin potential level exceeds 95% VREG (equivalent to the PWM duty of 95%) when the full drive is configured to Disable (SEL0 = High), the drivers outputs are turned off (the high-side pre-driver output is changed to High while the low-side pre-driver output is changed to Low). The drivers resume the outputs when the VREG potential falls under 90% (typ.).

During the full drive detection, the built-in digital filter on the PWMOUT pin is initialized, and the NDG pin output is pulled Low.

The PWMOUT pin continues behaving normally upon full drive detection, provided that, although for a short time, it is forcibly fixed to Low due to the internal delay of the IC at the time when the full drive disable is released.





#### 5.8 External Forced Off Input

Applying the Low input to the NDG pin allows the drivers to be turned off (the high-side pre-driver output is changed to High while the low-side pre-driver output is changed to Low).

During the external forced off input, the PWMOUT pin output is forcibly fixed to Low.



## Absolute Maximum Rating(Ta=25°C)

The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings.

Characteristics	Symbol	Pin	Ratings	Unit	Remarks	
	VB1	BIAS	-0.3 to +40	V	The rating over +24 V must be within 0.2 s.	
Power supply voltage	VB2	VREG	-0.3 to +6.0	V		
	VB3	VDD	-0.3 to +6.0	V	-0.3 V < VDD-VREG < 0.3 V	
	VIN1	PWMIN	-0.3 to BIAS+0.3	V	The rated voltage is less than 40 V. The rating over +24 V must be within 0.2 s.	
Input voltage	VIN2	СОМРР	-0.3 to BIAS+0.3	V	The rated voltage is less than +24 V.	
	VIN3	SEL1, TVIN	-0.3 to VREG+0.3	V	The rated voltage is less than +6.0 V	
	VIN4	SEL0, SEL2, NDG, SU, SV, SW, PWMOUT, TEST	-0.3 to VDD+0.3	V	The rated voltage is less than +6.0 V	
Output voltage	VOUT1	ouh, ovh, owh, oul, ovl, owl	-0.3 to BIAS+0.3	V	The rated voltage is less than 40 V. The rating over +24 V must be within 0.2 s.	
	VOUT2	NDG, PWMOUT	-0.3 to VDD+0.3	V	The rated voltage is less than +6.0 V	
	IOUT1	OUH, OVH, OWH, OUL, OVL, OWL	up to ±250	mA	Must not exceed the Power dissipation.	
Output ourrent	IOUT2	NDG, PWMOUT	up to 5	mA	Must not exceed the Power dissipation.	
Power dissipation	PD	_	See the figure below.	W		
Junction temperature	Tj	—	up to 150	°C		
Operating temperature	Topr	_	-40 to 125	°C		
Storage temperature	Tstg	—	-55 to 150	°C		

- Note: The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded during operation, even for an instant. Exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may damage any other equipment. Applications using the device should be designed such that the absolute maximum ratings will never be exceeded in any operating conditions. The device must be used within the specified operating range.
- Note : Ratings are presented with the marks; (minus) and + (plus) indicating the output current from the IC and the input current to the IC respectively, including the symbols.



Note : When mounted on the Toshiba typical board (50 mm  $\times$  50 mm  $\times$  1.6 mm, Cu = 40%).

Unless otherwise specified, Ta = -40 to +125°C, GND = PGND = 0 V, BIAS = 6 to 18 V, VREG and VDD must be shorted.

		1					
Characteristics	Symbol	Pin	Test Conditions	Min	Тур.	Max	Unit
<ul> <li>Power Consumption</li> </ul>							
IC power consumption	lbias	BIAS	TVIN and COMPP are tied to GND. Others have no load.		4.0	6.0	mA
♦ Constant Power Voltage							
Constant output voltage	Vreg	VREG	Iveg = 0 to -5 mA	4.75	5.00	5.25	V
VREG undervoltage detection threshold	VresL			4.30	4.50	4.70	V
VREG undervoltage detection hysteresis	VresS	VREG		0.10	0.15	0.20	V
Difference between the constant output voltage and VREG undervoltage detection release threshold	VdifH			0.15	0.35		V
<ul> <li>Pre-drivers</li> </ul>							
Internally generated PWM frequency	fpwm			17.0	20.0	23.0	kHz
High-side output voltage 1	VoH_pr1	OUH, OVH,	lout = -10 mA	BIAS -0.3	—	—	V
Low-side output voltage 1	VoL_pr1	OWH	lout = 10 mA			0.3	V
	VoH_pr2	OUL, OVL, OWL	lout = -10 mA BIAS = 6 to 16 V	BIAS -0.3		_	V
High-side output voltage 2			lout = -10 mA BIAS = 16 to 18 V	Vclmp -0.3			V
Low-side output voltage 2	VoL_pr2		lout = 10 mA	_	_	0.3	V
High-side diode-clamp voltage *1	VcImp	OUL, OVL, OWL	BIAS = up to 24 V lout = 0 mA (no load)	16 *1	18 *1	20 *1	V
Output off leakage current	lleak	OUH, OVH, OWH, OUL, OVL, OWL	Vin = 0 V to BIAS on Hi-z output	-10	_	10	μA
Output delay time for rising edge	TdlyR		In operating mode 2 See Figure 1	1	4	6	μS
Output delay time for falling edge	TdlyF	OUL, OVL, OWL	In operating mode 2 See Figure 1	_	3	5	μS
Pulse output cycle error	Tdiff		In operating mode 2 See Figure 2	-1	0	1	μS
♦ Sensor Input							
High input detection threshold	ViH_si	SU SV SW			_	0.8 ×VREG	V
Low input detection threshold	ViL_si	50, 50, 500		0.2 ×VREG			V
Low input current	liL_si	SU, SV, SW	VREG = 5 V, Vin = 0 V	-1.5	-1.0	-0.5	mA
Noise cancellation time width	Tnc_si	SU, SV, SW		—	10	—	μS

Note: Ratings are presented with the marks; – (minus) and + (plus) indicating the output current from the IC and the input current to the IC respectively, including the symbols.

\*1: The limit reflects the DC characteristics. Any particular event like a rapid fluctuation of the power supply is not considered.

Unless otherwise specified, Ta = -40 to +125 °C, GND = PGND = 0 V, BIAS = 6 to 18 V, VREG and VDD must be shorted.

Characteristics	Symbol	Pin	Test Conditions	Min	Тур.	Max	Unit
<ul> <li>PWM Duty Configuration</li> </ul>		4					
High input detection threshold	ViH_pH			0.60 ×BIAS	0.67 ×BIAS	0.73 ×BIAS	V
Low input detection threshold	ViL_pL			0.33 ×VREG	0.40 ×VREG	0.47 ×VREG	V
	foin		SEL1= High or Low	—	_	4.0	kHz
	ipin	FVIVIIIN	SEL1 = Open or Middle		20	23	kHz
High input current 1	liH_p1		SEL1 = High, BIAS = 12 V, Vin = BIAS	60	120	240	μA
Low input current 1	liL_p1		SEL1 = Low, BIAS = 12 V, Vin = 0 V	-240	-120	-60	μA
High input current 2	liH_p2		SEL1 = Open, BIAS = 12 V, Vin = BIAS	60	120	240	μA
Low input current 2	liL_p2		SEL1 = Open, BIAS = 12 V, Vin = 0 V	-240	-120	-60	μA
High output current	loH_po		When PWMOUT is High active ,VREG = 5.0 V and PWMOUT is 0 V input	-34	-25	-18	μA
Low output current	loL_po	PWMOUT	When PWMOUT is Low active, VREG = 5.0 V and PWMOUT is VREG input.	18	25	34	μΑ
Low output voltage	VoL_po	PWMOUT	lout = 1 mA where NDG = Low	_	0.1	0.3	V
♦ Control Input	<u></u>			L			
High input detection threshold 1	ViH	CW/CCW,		_	_	0.8 ×VREG	V
Low input detection threshold 1	ViL	SEL0, SEL2		0.2 ×VREG	_	_	V
High input detection threshold 2	ViH_s1			0.65 ×VREG	0.70 ×VREG	0.75 ×VREG	V
Low input detection threshold 2	ViL_s1	JELI		0.25 ×VREG	0.30 ×VREG	0.35 ×VREG	V
Low input current	liL_cc	CW/CCW	VREG = 5V, Vin = 0V	-200	-100	-50	μA
Low input current	liL_s0	SEL0	VREG = 5V, Vin = 0V	-200	-100	-50	μA
High input current	liH_s1		VREG = 5V, Vin = VREG	350	500	700	μA
Low input current	liL_s1	JELI	VREG = 5V, Vin = 0V	-700	-500	-350	μA
Low input current	liL_s2	SEL2	VREG = 5V, Vin = 0V	-200	-100	-50	μA
Filter pass time on the rapid start	Tpass	SEL2		_	0.3		s
Dead time for motor rotation direction switchover	Tdead	CW/CCW		_	50	_	μs

Note: Ratings are presented with the marks; – (minus) and + (plus) indicating the output current from the IC and the input current to the IC respectively, including the symbols.

Unless otherwise specified, Ta = -40 to +125°C, GND = PGND = 0 V, BIAS = 6 to 18 V, VREG and VDD must be shorted.

Characteristics	Symbol	Pin	Test Conditions	Min	Тур.	Max	Unit
<ul> <li>Error Detection (the external</li> </ul>	overcurrent o	detector for the	e motor driver)				
Overcurrent detection threshold 1	Vth_c1	COMPP		85	100	115	mV
Overcurrent detection threshold 2	Vth_c2	COMPP		170	200	230	mV
Output off time width for overcurrent detection threshold 1	Tof_c1	COMPP			50	_	μS
Output off time width for overcurrent detection threshold 2	Tof_c2	COMPP		_	200		μs
Required time for determining the fixed output off for overcurrent detection threshold 2	Toff2	COMPP		_	0.60		s
Input current	lin_cp	COMPP	Vin=0 to 4.5V	-5	_	5	μA
Noise cancellation time width for overcurrent detection 1	Tnc_c1	COMPP			3	_	μS
Noise cancellation time width for overcurrent detection 2	Tnc_c2	COMPP		_	1	_	μS
<ul> <li>Error Detection (the external</li> </ul>	thermal dete	ctor for the mo	otor driver)				
Thermal detection threshold	ViH_tv			0.40 ×VREG	0.44 ×VREG	0.48 ×VREG	V
Thermal detection release threshold	ViL_tv	IVIN		0.20 ×VREG	0.24 ×VREG	0.28 ×VREG	V
Input current	lin_tv	TVIN	Vin=0 to VREG	-5		5	μA
Noise cancellation time width for thermal detection	Tnc_tv	TVIN		—	10	—	μS
<ul> <li>Error Detection (IC thermal d</li> </ul>	letector)						
Thermal detection threshold	TsdH			_	165		°C
Thermal detection threshold hysteresis	TsdS	—			10	_	°C
<ul> <li>Error Detection (BIAS overvol)</li> </ul>	ltage and un	dervoltage det	tector)				
Overvoltage detection threshold	VsdH_H	BIAS		24.5	27.0	29.5	V
Undervoltage detection threshold	VsdL_L	DIAG		5.2	5.5	5.9	V

Note: Ratings are presented with the marks; – (minus) and + (plus) indicating the output current from the IC and the input current to the IC respectively, including the symbols.

Unless otherwise specified, Ta = -40 to +125 °C , GND = PGND = 0 V, BIAS = 6 to 18 V, VREG and VDD must be shorted.

				-							
Characteristics	Symbol	Pin	Test Conditions	Min	Тур.	Max	Unit				
Error Detection (the full drive detector)											
100% duty detection threshold	VdtyH		PWMOUT pin level	0.92 ×VREG	0.95 ×VREG	0.98 ×VREG	V				
100% duty detection release threshold hysteresis	VdtyS	PWMOUT	PWMOUT pin level	_	0.05 ×VREG	_	V				
Error Detection (the external forced off input detector)											
High input detection threshold	ViH_nd	NDC				0.8 ×VREG	V				
Low input detection threshold	ViL_nd	NDG		0.2 ×VREG	_	_	V				
High output voltage	VoH_nd	NDG	lout = 0 mA (no load)	VDD -0.3	VDD -0.1	_	V				
Low output voltage	VoL_nd		lout = 1 mA		0.1	0.3	V				
Low input current	liL_nd	NDG	VREG = 5 V, Vin = 0 V	-1000	-500	-250	μA				

Note: Ratings are presented with the marks; – (minus) and + (plus) indicating the output current from the IC and the input current to the IC respectively, including the symbols.

#### Figure 1





#### Figure 2







## **Typical Applications for Various Controls**

1) When running the motor driver with fixed 100% duty cycle using the internal PWM



2) When running the motor driver with any fixed duty cycle using the internal PWM



3) When running the motor driver using any external input PWM



- Note: In the application circuit example, part of the functional blocks or constants may be omitted or simplified for explanatory purposes.
- Note: The application circuit shown above is not intended to guarantee mass production. A thorough evaluation is required when designing an application circuit for mass production.



## TB9067FNG

## **Package Dimensions**

Unit: mm



Expanded View of the Lead Tip



Weight: 0.14 g (typ.)



## TOSHIBA

#### Notes

- Note: Some of the functional blocks, circuits, or constants in the block diagram may be omitted or simplified for explanatory purposes.
- Note: The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.
- Note: Timing charts may be simplified for explanatory purposes.
- Note: Ensure that the IC is mounted correctly as specified. Failing to observe the correct mounting procedure or requirements may damage the IC or target equipment.
- Note: The application circuits shown in this document are provided for reference purposes only. Thorough evaluation is required, especially at the mass production design stage. Toshiba does not grant any license to any industrial property rights by providing these examples of application circuits.
- Note: Components in the test circuits are only used to obtain and confirm the device characteristics. These components and circuits do not warrant to prevent the application equipment from malfunction or failure.

## **RESTRICTIONS ON PRODUCT USE**

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, and lifesaving and / or life supporting medical equipment. IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your TOSHIBA sales representative or contact us via our website.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
  applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without
  limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile
  technology products (mass destruction weapons). Product and related software and technology may be controlled under the
  applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the
  U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited
  except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

TOSHIBA ELECTRONIC DEVICES & STORAGE CORPORATION https://toshiba.semicon-storage.com/